## Schottky Barrier Diode, 2A, 40V Type

#### **FEATURES**

Forward Voltage : V<sub>F</sub>=0.485V (TYP.)

Forward Current :  $I_{F(AV)}$ =2A Repetitive Peak Reverse Voltage :  $V_{RM}$ =40V Rectification

**APPLICATIONS** 

Protection against reverse connection of battery

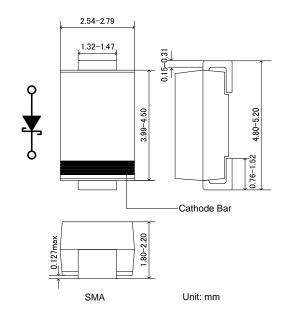
#### ABSOLUTE MAXIMUM RATINGS

Ta=25

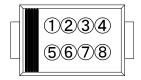
PARAMETER	SYMBOL	RATINGS	UNIT
Repetitive Peak Reverse Voltage	Vrm	40	V
Reverse Voltage (DC) VR		40	V
Forward Current (Average)	IF(AV) 2		Α
Non Continuous	inuous IFSM		Α
Forward Surge Current <sup>*1</sup>	IFSM	50	Α .
Junction Temperature	Tj	125	
Storage Temperature Range	Tstg	-55 ~ <b>+</b> 150	

<sup>\*1:</sup> Non continuous high amplitude 60Hz half-sine wave.

# PACKAGING INFORMATION



#### MARKING RULE



: 204S17(Product Number)

: Assembly Lot Number

#### **PRODUCT NAME**

PRODUCT NAME	DEVICE ORIENTATION		
XBS204S17 °	R : Embossed tape, standard feed		

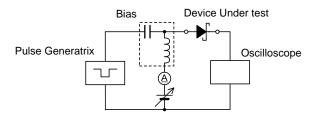
<sup>\*</sup> Please put the device orientation type "R".

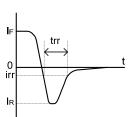
#### **ELECTRICAL CHARACTERISTICS**

Ta=25

PARAMETER SYMBOL	CVMDOL	SYMBOL TEST CONDITIONS	LIMITS		UNIT	
	STIVIBUL		MIN.	TYP.	MAX.	UNIT
Forward Voltage VF1 VF2	VF1	I <sub>F</sub> =200 μ A	-	0.15	-	V
	VF2	I <sub>F</sub> =2A	-	0.485	0.54	V
Reverse Current IR1	l <sub>R1</sub>	V <sub>R</sub> =20V	-	2.5	-	μA
	lR2	V <sub>R</sub> =40V		6	200	μА
Inter-Terminal Capacity	Ct	V <sub>R</sub> =1V , f=1MHz	-	180	-	pF
Reverse Recovery Time*2	trr	I <sub>F</sub> =I <sub>R</sub> =10mA , irr=1mA	-	51	-	ns

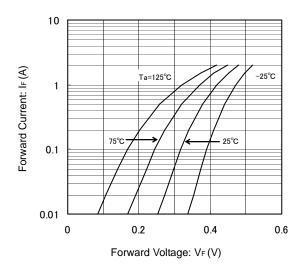
<sup>\*2 :</sup> trr measurement circuit



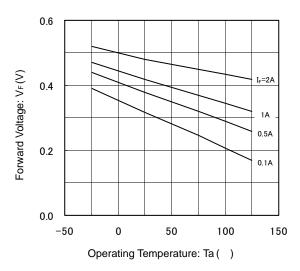


### TYPICAL PERFORMANCE CHARACTERISTICS

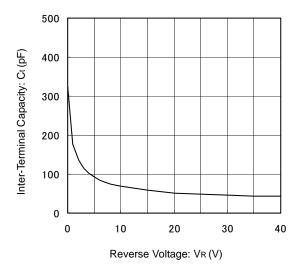
(1) Forward Current vs. Forward Voltage



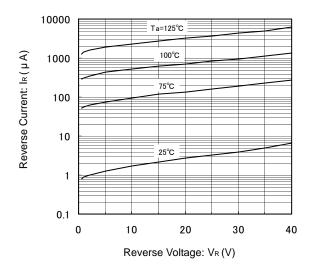
(3) Forward Voltage vs. Operating Temperature



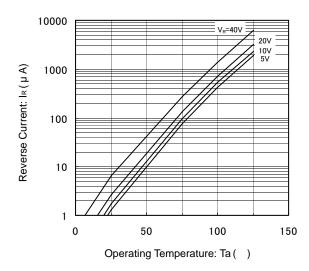
(5) Inter-Terminal Capacity vs. Reverse Voltage



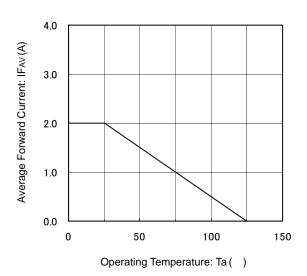
(2) Reverse Current vs. Reverse Voltage



(4) Reverse Current vs. Operating Temperature



(6) Average Forward Current vs. Operating Temperature



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